

ASSIGNMENT 1

EEE241 ANALOG I, 2010/2011

(1)

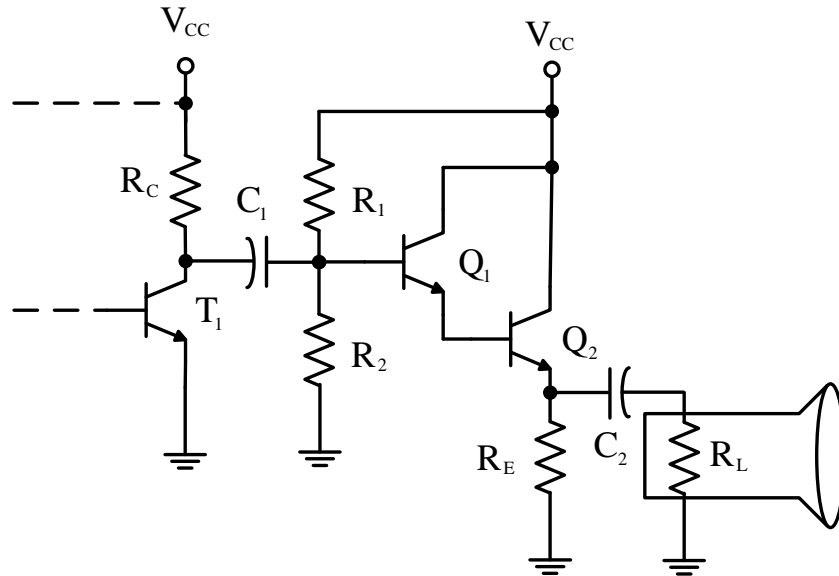


Figure 1

The emitter follower is often used as an interface between a circuit with a high output resistance and a low resistance load. In such an application, the emitter follower is called a buffer.

For example, suppose a common-emitter amplifier with a $1\text{ k}\Omega$ collector resistance (output resistance) must drive a low resistance load such as an 8Ω low power speaker. The circuit is shown in Figure 1. C_1 and C_2 are coupling capacitors. $V_{CC} = 12\text{ V}$, $V_T = 26\text{ mV}$ and $V_{BE} = 0.7\text{ V}$. Assume that $g_m = 0.2\text{ S}$ and $r_o \gg R_C$ for the CE circuit. For the Darlington emitter-follower, $R_1 = 10\text{ k}\Omega$, $R_2 = 22\text{ k}\Omega$, $R_E = 22\Omega$, $R_L = 8\Omega$, and $\beta_{DC} = \beta_{ac} = 100$ for each transistor.

Problem:

- a. Calculate the open-circuit voltage gain of the CE circuit.
- b. Calculate the voltage gain of the CE circuit if it is directly connected to the 8Ω speaker (no Darlington emitter-follower included).
- c. Give comments based on the results of 1 and 2.
- d. Calculate the voltage gain of the Darlington emitter-follower circuit.
- e. Calculate the voltage gain of the whole circuit in Figure 1.

(2) (a) A cascode circuit is shown in Figure 2. What is the minimum value of V_{BIAS} required for a cascode amplifier operating at $I = 100\mu\text{A}$? Let $\mu_n C_{ox} = 300\mu\text{A}/\text{V}^2$, $\frac{W}{L} = 10$ and $V_t = 0.6\text{ V}$.

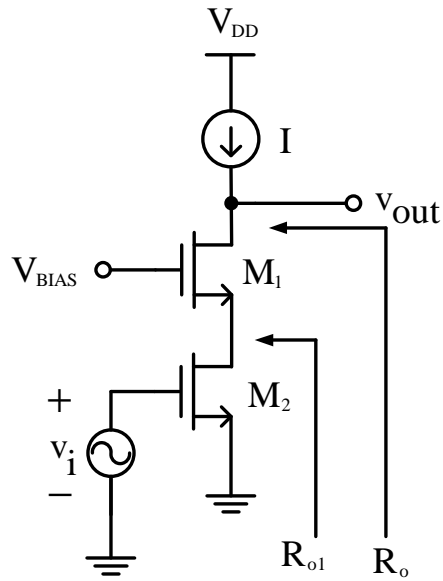


Figure 2

(b) Consider the same cascode amplifier shown in Figure 2.

$I = 100\mu\text{A}$ and for each transistor, $\frac{W}{L} = \frac{5\mu\text{m}}{0.5\mu\text{m}} = 10$, $V_A = 10\text{V}$, and $\mu_n C_{ox} = 190\mu\text{A}/\text{V}^2$. Find R_{o1} and R_o .

(3) Determine the small-signal voltage gain of the multistage cascade circuit shown in Figure 3. The transistor parameters are $K_1 = 0.5\text{ mA}/\text{V}^2$, $K_2 = 0.2\text{ mA}/\text{V}^2$, $V_{t1} = V_{t2} = 1.2\text{ V}$ and $\lambda_1 = \lambda_2 = 0$. $K_n = \frac{\mu_n C_{ox}}{2} \frac{W}{L}$.

Neglect r_o . The quiescent drain currents are $I_{D1} = 0.2\text{ mA}$ and $I_{D2} = 0.5\text{ mA}$.

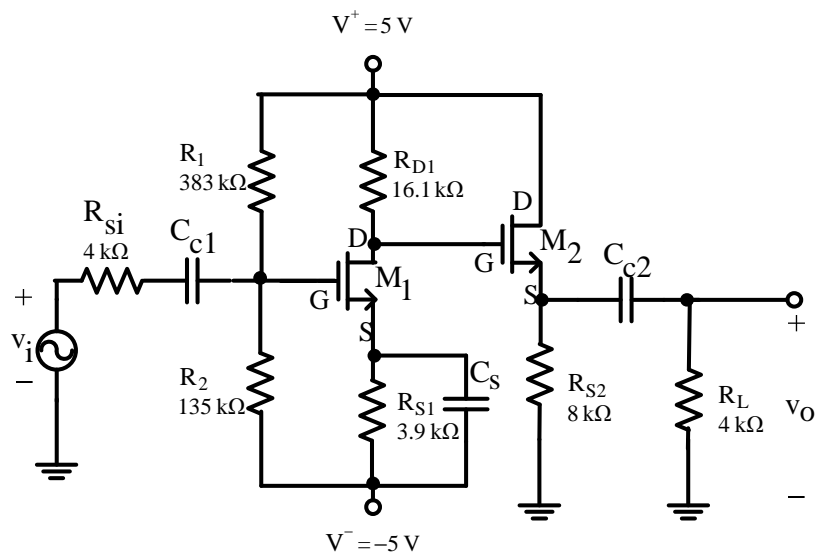


Figure 3